



6-Pin DIP Optoisolators Transistor Output

The 4N25/A, 4N26, 4N27 and 4N28 devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector.

- Most Economical Optoisolator Choice for Medium Speed, Switching Applications
- Meets or Exceeds All JEDEC Registered Specifications
- *To order devices that are tested and marked per VDE 0884 requirements, the suffix "V" must be included at end of part number. VDE 0884 is a test option.*

Applications

- General Purpose Switching Circuits
- Interfacing and coupling systems of different potentials and impedances
- I/O Interfacing
- Solid State Relays

MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
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INPUT LED

Reverse Voltage	V_R	3	Volts
Forward Current — Continuous	I_F	60	mA
LED Power Dissipation @ $T_A = 25^\circ\text{C}$ with Negligible Power in Output Detector Derate above 25°C	P_D	120	mW
		1.41	mW/ $^\circ\text{C}$

OUTPUT TRANSISTOR

Collector–Emitter Voltage	V_{CEO}	30	Volts
Emitter–Collector Voltage	V_{ECO}	7	Volts
Collector–Base Voltage	V_{CBO}	70	Volts
Collector Current — Continuous	I_C	150	mA
Detector Power Dissipation @ $T_A = 25^\circ\text{C}$ with Negligible Power in Input LED Derate above 25°C	P_D	150	mW
		1.76	mW/ $^\circ\text{C}$

TOTAL DEVICE

Isolation Surge Voltage(1) (Peak ac Voltage, 60 Hz, 1 sec Duration)	V_{ISO}	7500	Vac(pk)
Total Device Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	250 2.94	mW mW/ $^\circ\text{C}$
Ambient Operating Temperature Range(2)	T_A	-55 to +100	$^\circ\text{C}$
Storage Temperature Range(2)	T_{stg}	-55 to +150	$^\circ\text{C}$
Soldering Temperature (10 sec, 1/16" from case)	T_L	260	$^\circ\text{C}$

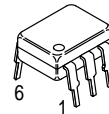
1. Isolation surge voltage is an internal device dielectric breakdown rating. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.
2. Refer to Quality and Reliability Section in Opto Data Book for information on test conditions.

Preferred devices are Motorola recommended choices for future use and best overall value. GlobalOptoisolator is a trademark of Motorola, Inc.

4N25*
4N25A*
4N26*
[CTR = 20% Min]
4N27
4N28
[CTR = 10% Min]

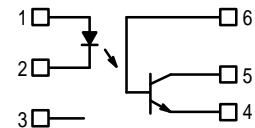
*Motorola Preferred Devices

STYLE 1 PLASTIC



STANDARD THRU HOLE
CASE 730A-04

SCHEMATIC



- PIN 1. LED ANODE
2. LED CATHODE
3. N.C.
4. EMITTER
5. COLLECTOR
6. BASE

4N25 4N25A 4N26 4N27 4N28

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)⁽¹⁾

Characteristic	Symbol	Min	Typ ⁽¹⁾	Max	Unit	
INPUT LED						
Forward Voltage (I _F = 10 mA)	V _F	T _A = 25°C	—	1.15	1.5	Volts
		T _A = -55°C	—	1.3	—	
		T _A = 100°C	—	1.05	—	
Reverse Leakage Current (V _R = 3 V)	I _R	—	—	100	μA	
Capacitance (V = 0 V, f = 1 MHz)	C _J	—	18	—	pF	

OUTPUT TRANSISTOR

Collector–Emitter Dark Current (V _{CE} = 10 V, T _A = 25°C)	4N25,25A,26,27	I _{CEO}	—	1	50	nA
	4N28		—	1	100	
(V _{CE} = 10 V, T _A = 100°C)	All Devices	I _{CEO}	—	1	—	μA
Collector–Base Dark Current (V _{CB} = 10 V)		I _{CBO}	—	0.2	—	nA
Collector–Emitter Breakdown Voltage (I _C = 1 mA)		V _{(BR)CEO}	30	45	—	Volts
Collector–Base Breakdown Voltage (I _C = 100 μA)		V _{(BR)CBO}	70	100	—	Volts
Emitter–Collector Breakdown Voltage (I _E = 100 μA)		V _{(BR)ECO}	7	7.8	—	Volts
DC Current Gain (I _C = 2 mA, V _{CE} = 5 V)		h _{FE}	—	500	—	—
Collector–Emitter Capacitance (f = 1 MHz, V _{CE} = 0)		C _{CE}	—	7	—	pF
Collector–Base Capacitance (f = 1 MHz, V _{CB} = 0)		C _{CB}	—	19	—	pF
Emitter–Base Capacitance (f = 1 MHz, V _{EB} = 0)		C _{EB}	—	9	—	pF

COUPLED

Output Collector Current (I _F = 10 mA, V _{CE} = 10 V)	I _C (CTR) ⁽²⁾	2 (20) 1 (10)	7 (70) 5 (50)	— —	mA (%)
4N25,25A,26 4N27,28					
Collector–Emitter Saturation Voltage (I _C = 2 mA, I _F = 50 mA)	V _{CE(sat)}	—	0.15	0.5	Volts
Turn–On Time (I _F = 10 mA, V _{CC} = 10 V, R _L = 100 Ω) ⁽³⁾	t _{on}	—	2.8	—	μs
Turn–Off Time (I _F = 10 mA, V _{CC} = 10 V, R _L = 100 Ω) ⁽³⁾	t _{off}	—	4.5	—	μs
Rise Time (I _F = 10 mA, V _{CC} = 10 V, R _L = 100 Ω) ⁽³⁾	t _r	—	1.2	—	μs
Fall Time (I _F = 10 mA, V _{CC} = 10 V, R _L = 100 Ω) ⁽³⁾	t _f	—	1.3	—	μs
Isolation Voltage (f = 60 Hz, t = 1 sec) ⁽⁴⁾	V _{ISO}	7500	—	—	Vac(pk)
Isolation Resistance (V = 500 V) ⁽⁴⁾	R _{ISO}	10 ¹¹	—	—	Ω
Isolation Capacitance (V = 0 V, f = 1 MHz) ⁽⁴⁾	C _{ISO}	—	0.2	—	pF

1. Always design to the specified minimum/maximum electrical limits (where applicable).

2. Current Transfer Ratio (CTR) = I_C/I_F × 100%.

3. For test circuit setup and waveforms, refer to Figure 11.

4. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

TYPICAL CHARACTERISTICS

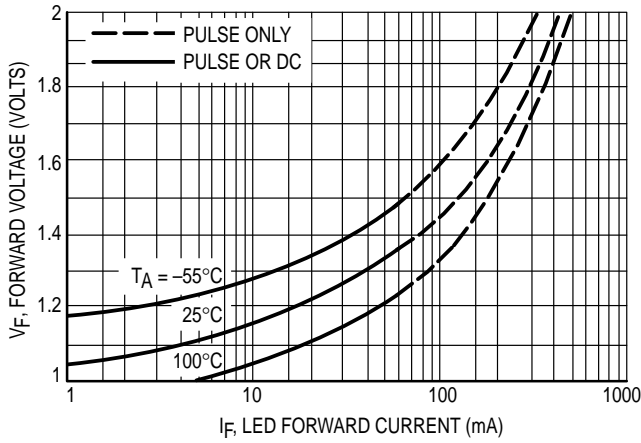


Figure 1. LED Forward Voltage versus Forward Current

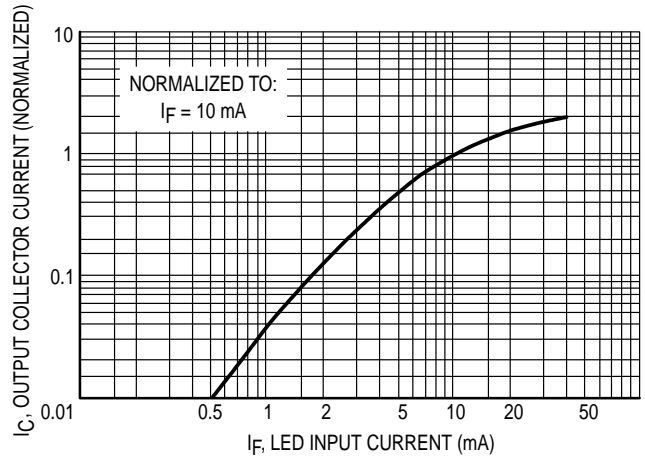


Figure 2. Output Current versus Input Current

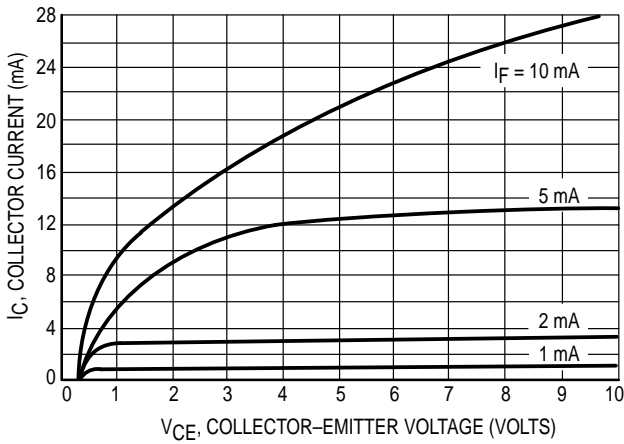


Figure 3. Collector Current versus Collector-Emitter Voltage

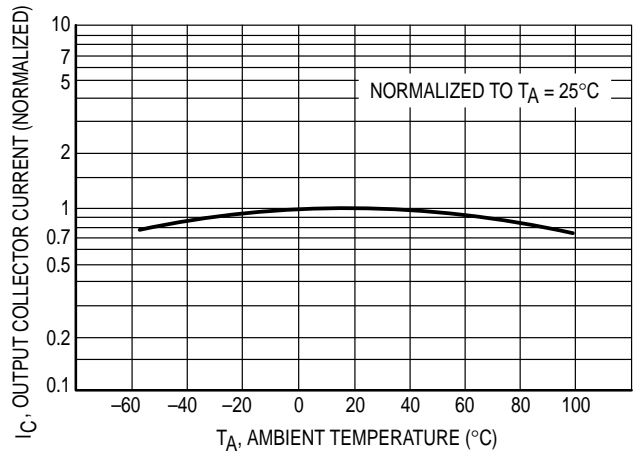


Figure 4. Output Current versus Ambient Temperature

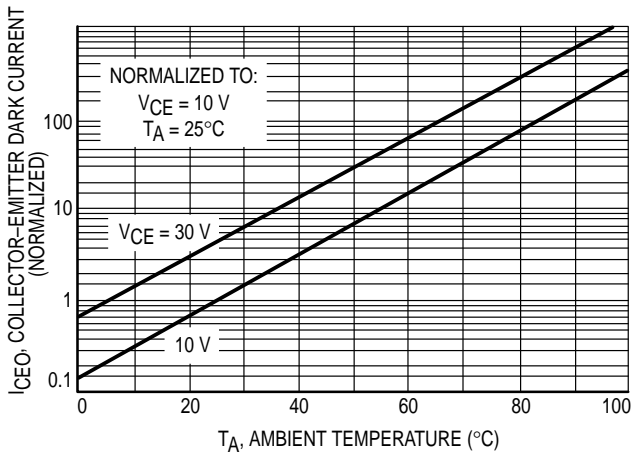


Figure 5. Dark Current versus Ambient Temperature

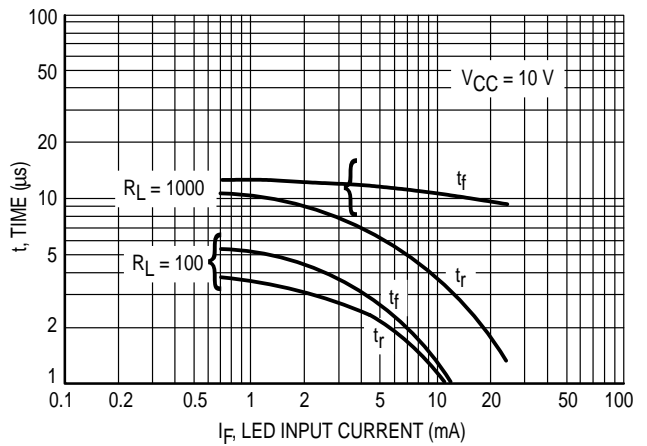


Figure 6. Rise and Fall Times (Typical Values)

4N25 4N25A 4N26 4N27 4N28

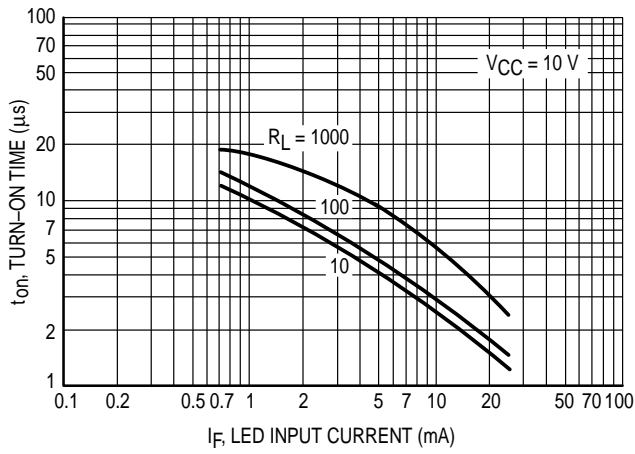


Figure 7. Turn-On Switching Times (Typical Values)

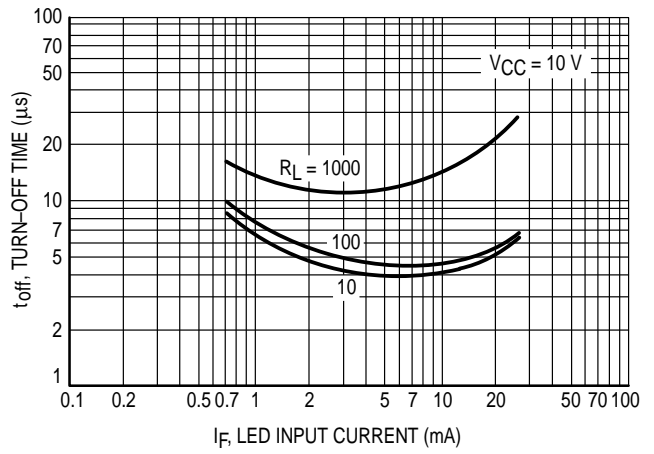


Figure 8. Turn-Off Switching Times (Typical Values)

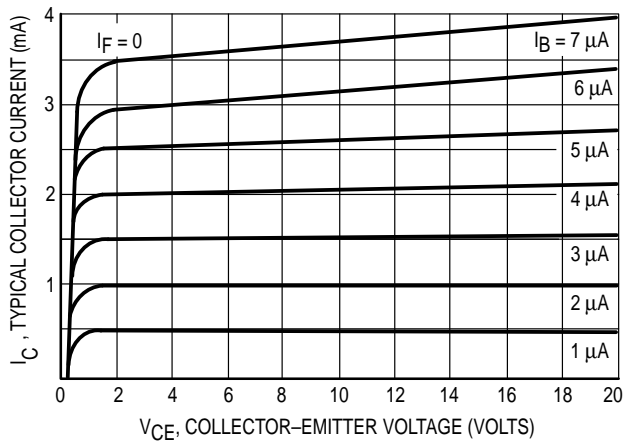


Figure 9. DC Current Gain (Detector Only)

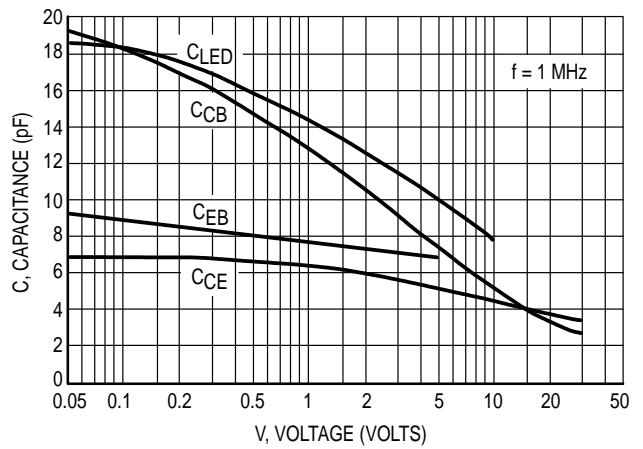


Figure 10. Capacitances versus Voltage

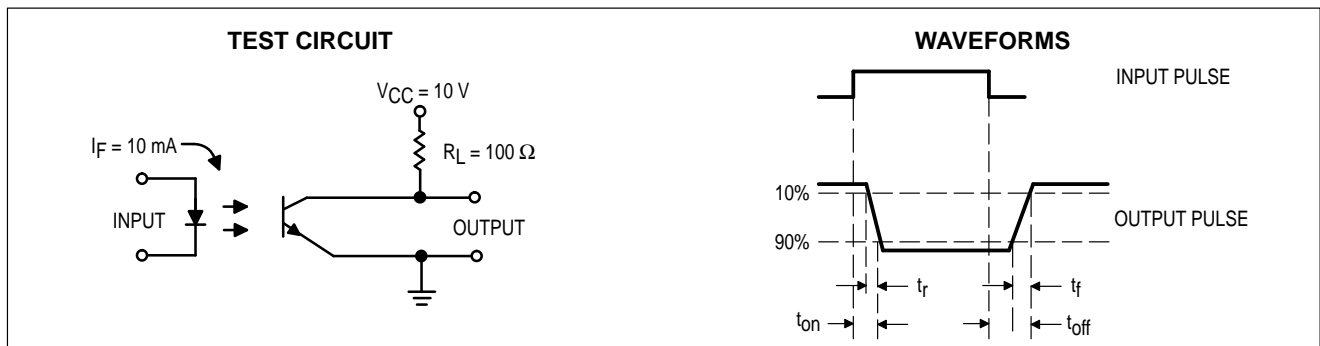
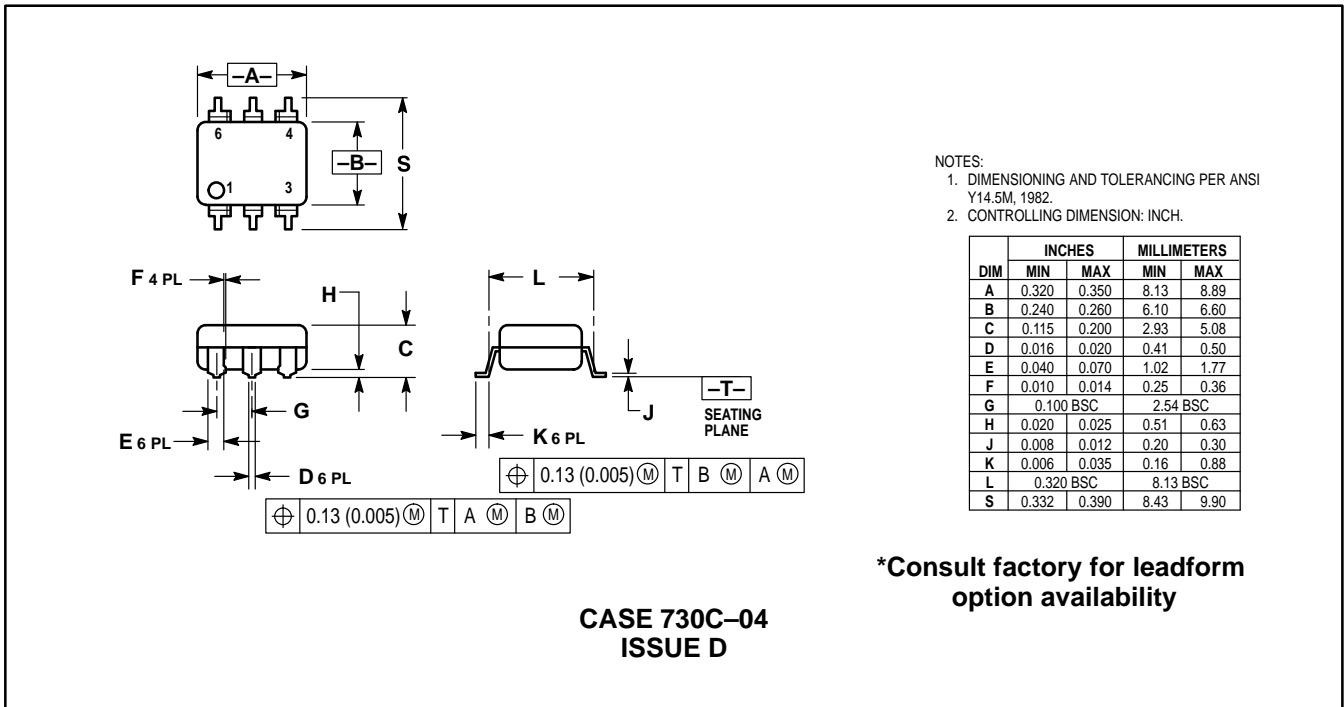
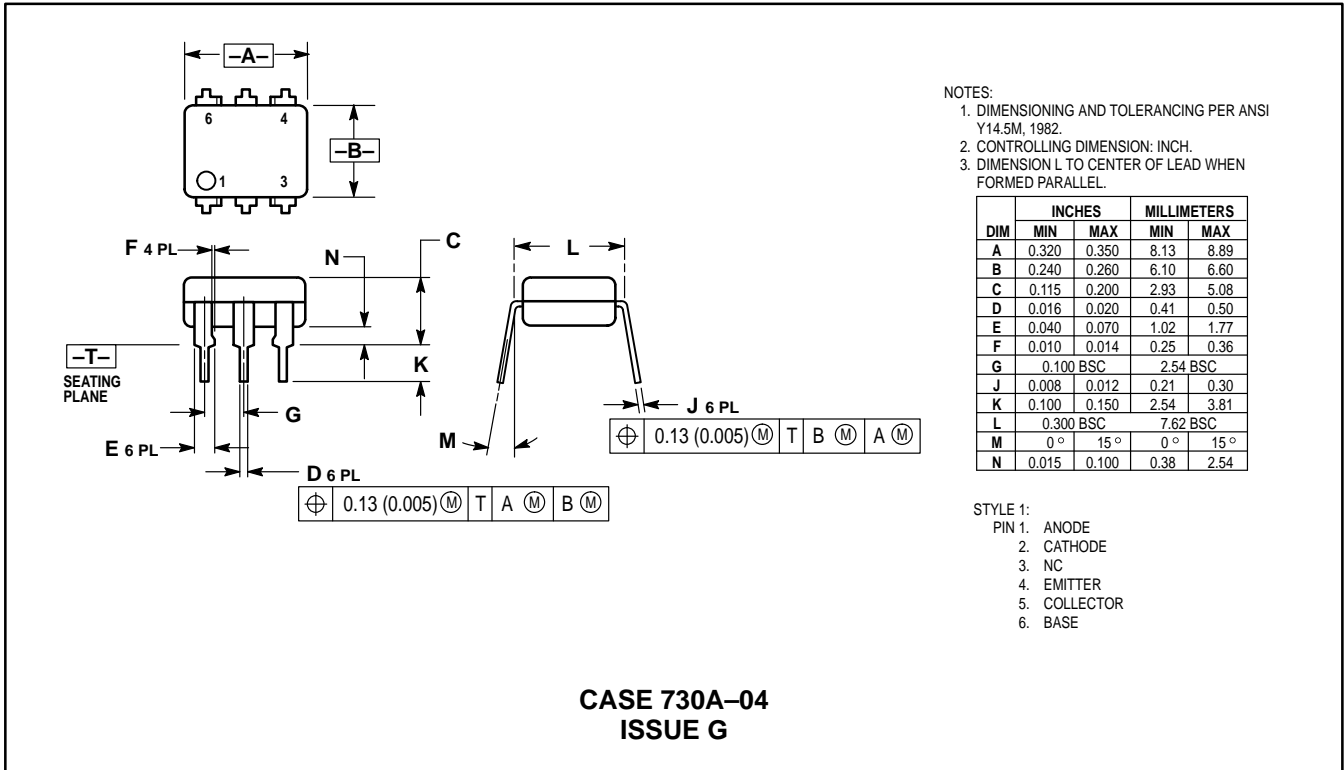


Figure 11. Switching Time Test Circuit and Waveforms

4N25 4N25A 4N26 4N27 4N28

PACKAGE DIMENSIONS



4N25 4N25A 4N26 4N27 4N28



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.320	0.350	8.13	8.89
B	0.240	0.260	6.10	6.60
C	0.115	0.200	2.93	5.08
D	0.016	0.020	0.41	0.50
E	0.040	0.070	1.02	1.77
F	0.010	0.014	0.25	0.36
G	0.100 BSC		2.54 BSC	
J	0.008	0.012	0.21	0.30
K	0.100	0.150	2.54	3.81
L	0.400	0.425	10.16	10.80
N	0.015	0.040	0.38	1.02

***Consult factory for leadform option availability**

**CASE 730D-05
ISSUE D**

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